Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

Between 0.140 inches and 0.180 inches

Terminal Length:

1.000 inches

Overall Diameter:

Between 0.060 inches and 0.080 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-2.0 breakdown voltage, dc

Current Rating Per Characteristic:

100.00 microamperes forward current, average peak

Power Rating Per Characteristic:

100.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Test Data Document:

08771-19a116052 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0